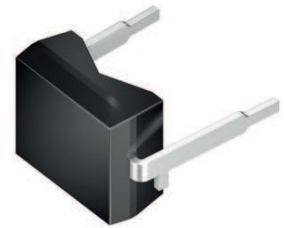# Silicon PIN Photodiode with Daylight Blocking Filter
Version 1.5

BPW 34 F

Features:

- Especially suitable for the wavelength range of 780 nm to 1100 nm
- Short switching time (typ. 20 ns)
- DIL plastic package with high packing density

Applications

- IR remote control of hi-fi and TV sets, dimmers, remote controls of various equipment
- Photointerrupters

Ordering Information

Type:	Photocurrent I_P [μA] $\lambda = 950$ nm, $E_e = 1$ mW/cm^2, $V_R = 5$ V	Ordering Code
BPW 34 F	50 ($\geq$ 40)	Q62702P0929

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Maximum Ratings (T_A = 25 °C)

| Parameter	Symbol	Values	Unit
Operating and storage temperature range	T_{op}; T_{stg}	-40 ... 100	°C
Reverse voltage	V_R	16	V
Reverse voltage (t < 2 min)	V_R	32	V
Total Power dissipation	P_{tot}	150	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V_{ESD}	2000	V

Characteristics (T_A = 25 °C)

Parameter		Symbol	Values	Unit
Photocurrent	(typ (min))	I_P	50 (≥ 40)	µA
Wavelength of max. sensitivity	(typ)	$\lambda_{S\,max}$	950	nm
Spectral range of sensitivity	(typ)	$\lambda_{10\%}$	(typ) 780 ... 1100	nm
Radiant sensitive area	(typ)	A	7.02	mm^2
Dimensions of radiant sensitive area	(typ)	L x W	2.65 x 2.65	mm x mm
Half angle	(typ)	φ	± 60	°
Dark current (V_R = 10 V)	(typ (max))	I_R	2 (≤ 30)	nA
Spectral sensitivity of the chip (λ = 950 nm)	(typ)	$S_{\lambda\,typ}$	0.7	A / W
Quantum yield of the chip (λ = 950 nm)	(typ)	η	0.91	Electrons /Photon
Open-circuit voltage (E_e = 0.5 mW/cm^2, λ = 950 nm)	(typ (min))	V_O	330 (≥ 275)	mV
Short-circuit current (E_e = 0.5 mW/cm^2, λ = 950 nm)	(typ)	I_{SC}	25	µA
Rise and fall time (V_R = 5 V, R_L = 50 Ω, λ = 850 nm, I_P = 800 µA)	(typ)	t_r, t_f	0.02	µs
Forward voltage (I_F = 100 mA, E = 0)	(typ)	V_F	1.3	V
Capacitance (V_R = 0 V, f = 1 MHz, E = 0)	(typ)	C_0	72	pF
Temperature coefficient of V_O	(typ)	TC_V	-2.6	mV / K

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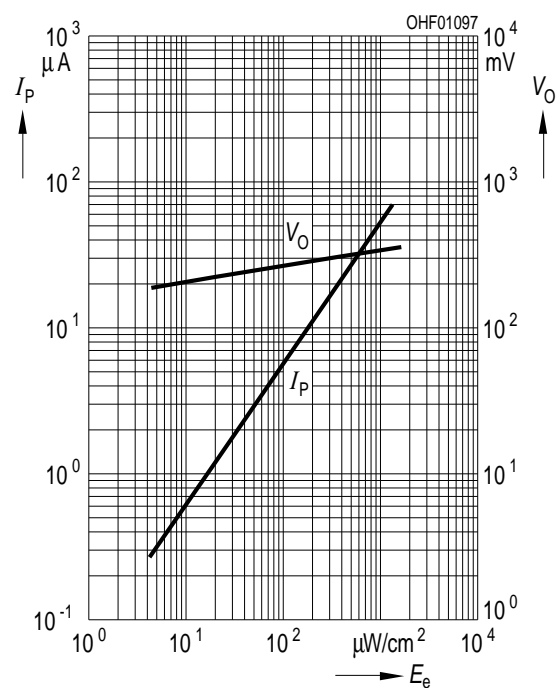| Parameter		Symbol	Values	Unit
Temperature coefficient of I_{SC} ($\lambda = 950$ nm)	(typ)	TC_I	0.18	% / K
Noise equivalent power ($V_R = 10$ V, $\lambda = 950$ nm)	(typ)	NEP	0.036	pW / $Hz^{1/2}$
Detection limit ($V_R = 10$ V, $\lambda = 950$ nm)	(typ)	D^*	7.3e12	cm x $Hz^{1/2}$ / W

Relative Spectral Sensitivity [1] *page 7*

$S_{rel} = f(\lambda)$
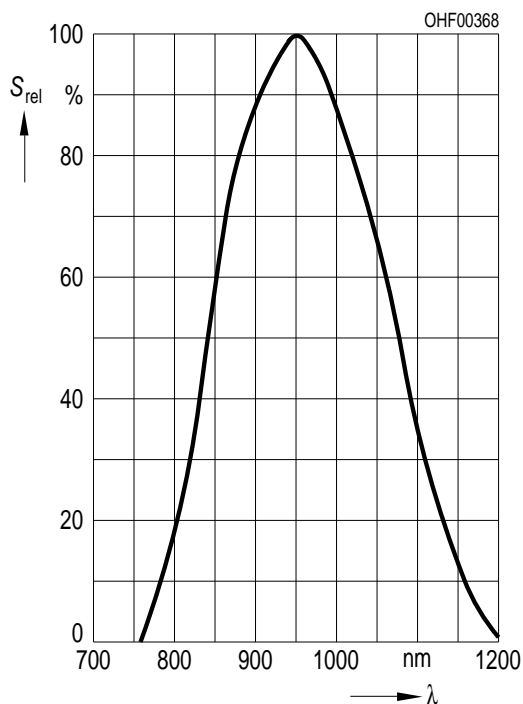
Photocurrent / Open-Circuit Voltage [1] *page 7*

I_P ($V_R = 5$ V) / $V_O = f(E_e)$

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Power Consumption

$P_{tot} = f(T_A)$

OHF00394

Dark Current [1] *page 7*

$I_R = f(V_R)$, $E = 0$

OHF00080

Capacitance [1] *page 7*

$C = f(V_R)$, $f = 1$ MHz, $E = 0$

OHF00081
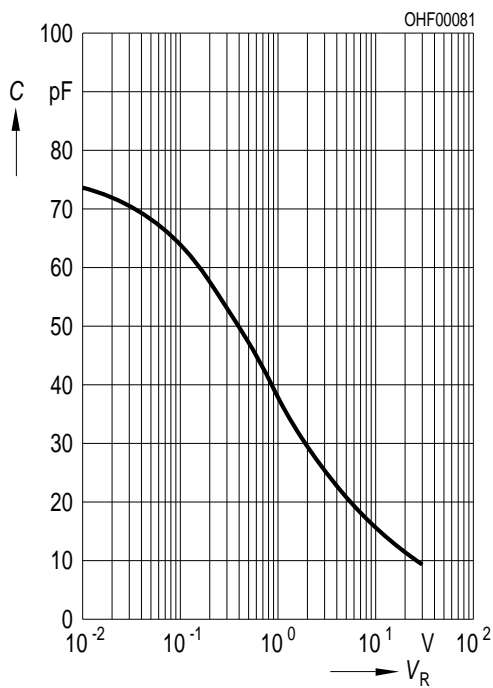
Dark Current [1] *page 7*

$I_R = f(T_A)$, $V_R = 10$ V, $E = 0$

OHF05717

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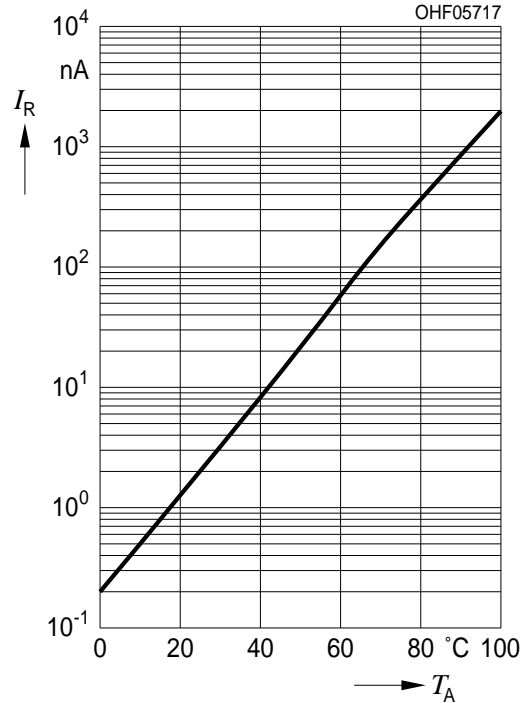
Directional Characteristics [1] *page 7*

$S_{rel} = f(\phi)$

OHF01402

Package Outline

C63062-A365-A6..-13
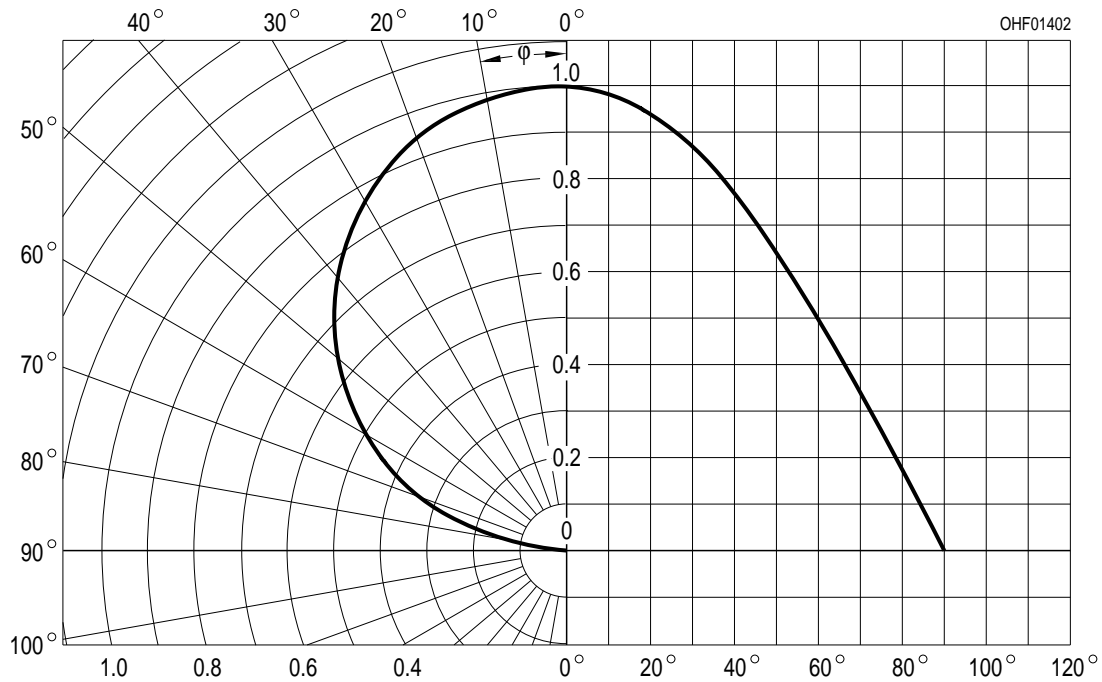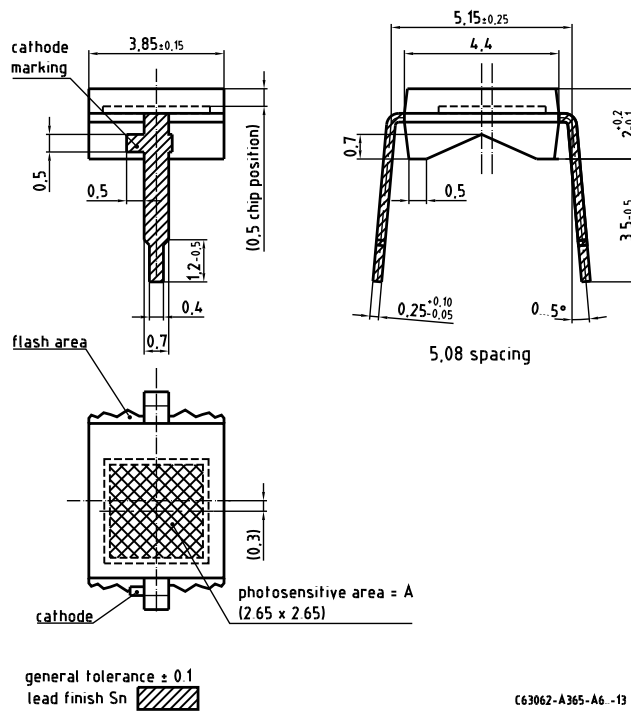
Dimensions in mm.
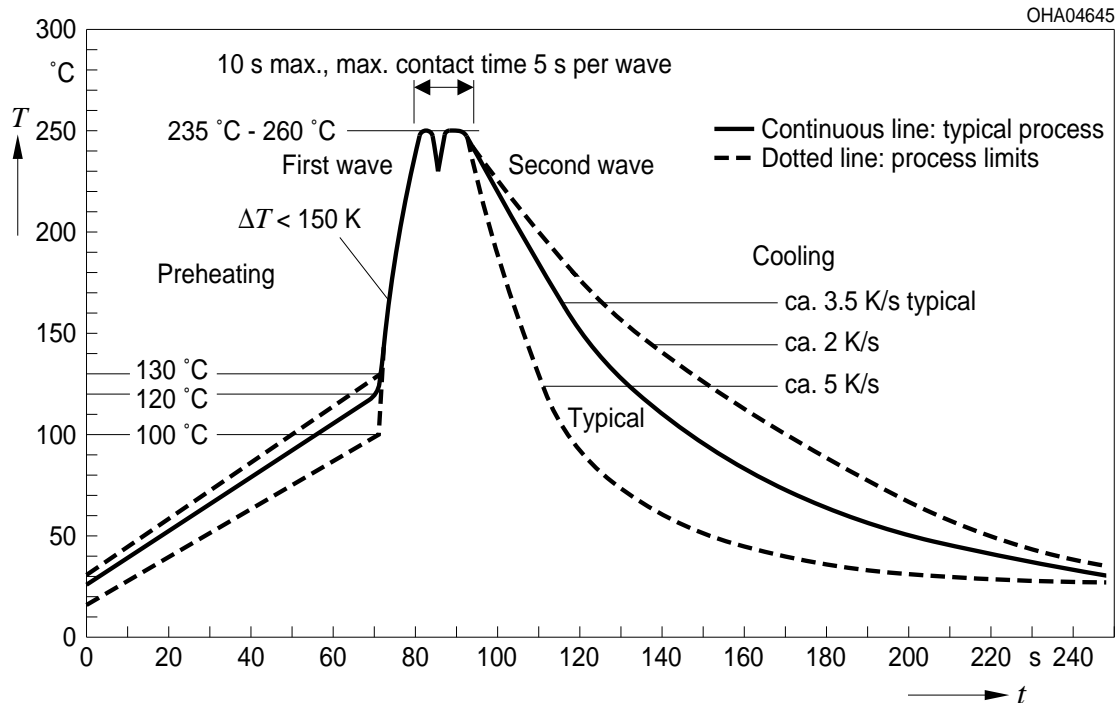
Package

DIL, Epoxy

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Approximate Weight:

78 mg

TTW Soldering

IEC-61760-1 TTW

OHA04645

Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose!

Critical components* may only be used in life-support devices** or systems with the express written approval of OSRAM OS.

*) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

**) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

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Glossary

[1] **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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EU RoHS and China RoHS compliant product

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